



DMG3414U

N-CHANNEL ENHANCEMENT MODE MOSFET

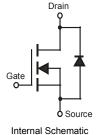
Features

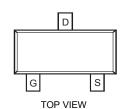
- Low On-Resistance
- 25mΩ @ V_{GS} = 4.5V
- 29mΩ @ V_{GS} = 2.5V
- 37mΩ @ V_{GS} = 1.8V
- Low Input Capacitance
- · Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish Matte Tin annealed over Copper leadframe.
 Solderable per MIL-STD-202, Method 208 ³
- Terminals Connections: See Diagram Below
- Weight: 0.008 grams (approximate)







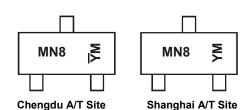
Part Number	Case	Packaging
DMG3414U-7	SOT23	3000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

Ordering Information (Note 4)



MN8 = Product Type Marking Code YM = Date Code Marking for SAT (Shanghai Assembly/ Test site) \overline{Y} M = Date Code Marking for CAT (Chengdu Assembly/ Test site) Y or \overline{Y} = Year (ex: A = 2013)

M = Month (ex: 9 = September)

Date Code Key

Date Code ito												
Year	200	9	2010		2011	20	12	2013		2014	2	2015
Code	W		Х		Υ	- 2	Z	Α		В		С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characte	eristic		Symbol	Value	Units
Drain-Source Voltage			V _{DSS}	20	V
Gate-Source Voltage		V _{GSS}	±8	V	
Continuous Drain Current (Note 5)	Steady $T_A = +25^{\circ}C$ State $T_A = +70^{\circ}C$			4.2 3.2	Α
Pulsed Drain Current (Note 6)		I _{DM}	30	А	

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	0.78	W
Thermal Resistance, Junction to Ambient @T _A = +25°C	$R_{\theta JA}$	162	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

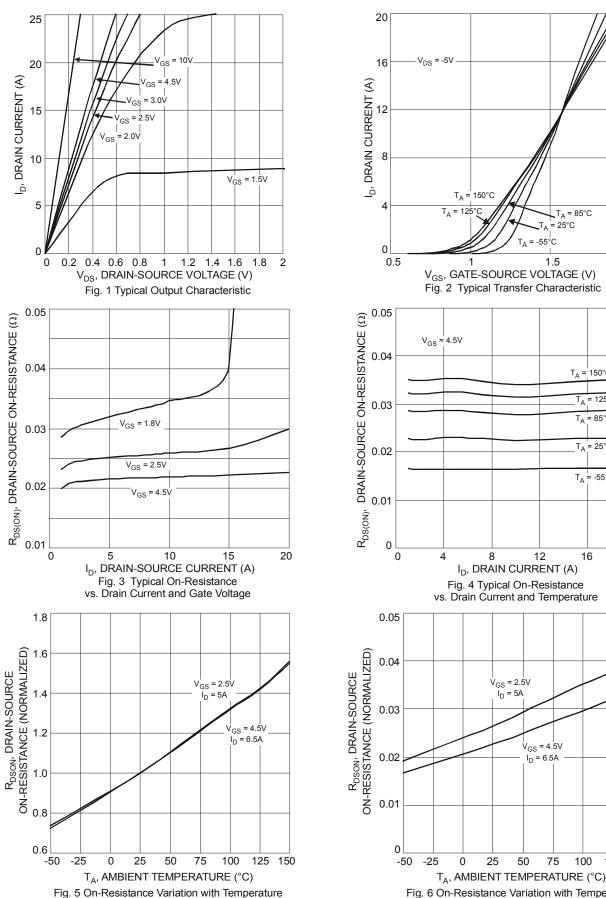
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 7)								
Drain-Source Breakdown Voltage	BV _{DSS}	20	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$		
Zero Gate Voltage Drain Current T _J = 25°C	I _{DSS}	_	_	1.0	μA	V _{DS} = 20V, V _{GS} = 0V		
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 8V, V_{DS} = 0V$		
ON CHARACTERISTICS (Note 7)								
Gate Threshold Voltage	V _{GS(th)}	0.5	_	0.9	V	V _{DS} = V _{GS} , I _D = 250μA		
		_	19	25		$V_{GS} = 4.5V, I_D = 8.2A$		
Static Drain-Source On-Resistance	R _{DS} (ON)		22	29	mΩ	$V_{GS} = 2.5V, I_D = 3.3A$		
			28	37		$V_{GS} = 1.8V, I_D = 2.0A$		
Forward Transfer Admittance	Y _{fs}	_	7	_	S	$V_{DS} = 10V, I_{D} = 4A$		
DYNAMIC CHARACTERISTICS (Note 8)			•	•	•			
Input Capacitance	C _{iss}	_	829.9	_	pF			
Output Capacitance	Coss	_	85.3	_	pF	$V_{DS} = 10V, V_{GS} = 0V$ f = 1.0MHz		
Reverse Transfer Capacitance	C _{rss}	_	81.2	_	pF	1 - 1.00012		
Total Gate Charge	Qg	_	9.6	_	nC			
Gate-Source Charge	Q_{gs}	_	1.5	_	nC	$V_{GS} = 4.5V, V_{DS} = 10V, I_D = 8.2A$		
Gate-Drain Charge	Q_{gd}	_	3.5	_	nC	1		
Turn-On Delay Time	t _{D(on)}	_	8.1	_	ns			
Turn-On Rise Time	t _r	_	8.3	_	ns	V _{DD} = 10V, V _{GS} = 4.5V,		
Turn-Off Delay Time	t _{D(off)}	_	40.1		ns	$R_L = 10\Omega$, $R_G = 6\Omega$, $I_D = 1A$		
Turn-Off Fall Time	tf		9.6	_	ns			

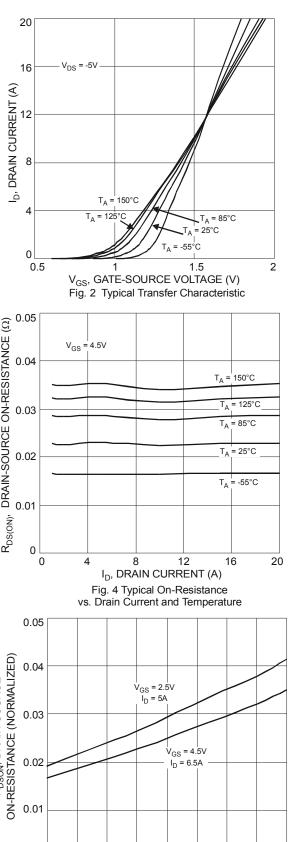
Notes:

- 5. Device mounted on FR-4 PCB with 2oz. Copper and test pulse width $t \le 10s$.

- Severe minimized in the first state of the fir







50

75

100

25

125 150



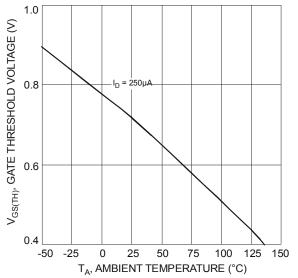
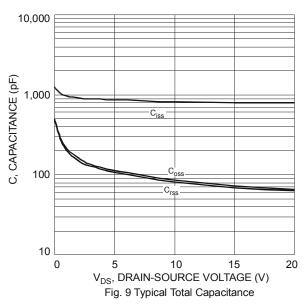
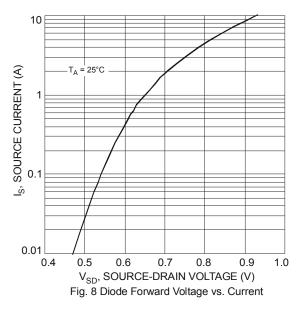


Fig. 7 Gate Threshold Variation vs. Ambient Temperature





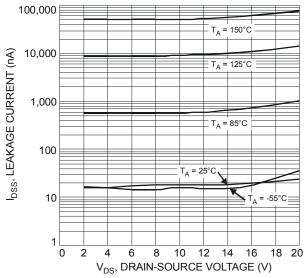


Fig. 10 Typical Leakage Current vs. Drain-Source Voltage

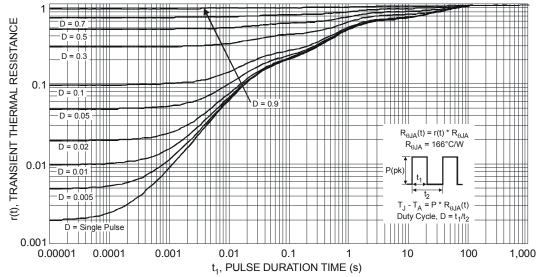
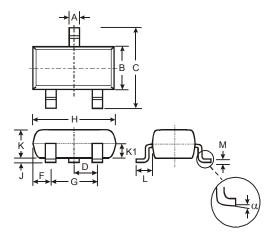


Fig. 11 Transient Thermal Response



Package Outline Dimensions

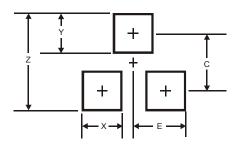
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



	SOT-23							
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
K	0.903	1.10	1.00					
K1	-	-	0.400					
L	0.45	0.61	0.55					
M	0.085	0.18	0.11					
α	0°	8°	-					
All	All Dimensions in mm							

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35



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